

RELIABILITY REPORT FOR MAX2014ETA+ PLASTIC ENCAPSULATED DEVICES

September 9, 2009

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Approved by
Ken Wendel
Quality Assurance
Director, Reliability Engineering



Conclusion

The MAX2014ETA+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

Table of Contents

II.Manufacturing Information

III.Packaging Information

.....Attachments

V.Quality Assurance Information VI.Reliability Evaluation IV.Die Information

I. Device Description

A. General

The MAX2014 complete multistage logarithmic amplifier is designed to accurately convert radio-frequency (RF) signal power in the 50MHz to 1000MHz frequency range to an equivalent DC voltage. The outstanding dynamic range and precision over temperature of this log amplifier make it particularly useful for a variety of base-station and other wireless applications, including automatic gain control (AGC), transmitter power measurements, and received signal-strength indication (RSSI) for terminal devices. The MAX2014 can also be operated in a controller mode where it measures, compares, and controls the output power of a variable-gain amplifier as part of a fully integrated AGC loop. This logarithmic amplifier provides much wider measurement range and superior accuracy compared to controllers based on diode detectors, while achieving excellent temperature stability over the full -40°C to +85°C operating range.



II. Manufacturing Information

A. Description/Function:	50MHz to 1000MHz, 75dB Logarithmic Detector/Controller
B. Process:	G4
C. Number of Device Transistors:	

Oregon

July 21, 2006

Philippines, Thailand, Malaysia

- D. Fabrication Location:
- E. Assembly Location:
- F. Date of Initial Production:

III. Packaging Information

A. Package Type:	8-pin TDFN 3x3
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive Epoxy
E. Bondwire:	Gold (1.2 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-2273
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	54°C/W
K. Single Layer Theta Jc:	8.3°C/W
L. Multi Layer Theta Ja:	41°C/W
M. Multi Layer Theta Jc:	8.3°C/W

IV. Die Information

A. Dimensions:	62 X 84 mils
B. Passivation:	Si ₃ N ₄
C. Interconnect:	Au
D. Backside Metallization:	None
E. Minimum Metal Width:	1.2 microns (as drawn) Metal 1, 2 & 3 5.6 microns (as drawn) Metal 4
F. Minimum Metal Spacing:	1.6 microns (as drawn) Metal 1, 2 & 3, 4.2 microns (as drawn) Metal 4
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw



 0.1% For all Visual Defects.

 C. Observed Outgoing Defect Rate:
 < 50 ppm</td>

 D. Sampling Plan:
 Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 150°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{\frac{1.83}{192 \text{ x } 4340 \text{ x } 45 \text{ x } 2}}_{\text{(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)}$ $\lambda = 10.6 \text{ x } 10^{-9}$ $\lambda = 10.6 \text{ F.I.T. (60\% confidence level @ 25°C)}$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the G4 Process results in a FIT Rate of 0.02 @ 25C and 0.37 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The CR11 die type has been found to have all pins able to withstand a HBM transient pulse of +/-500 V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250 mA.



Table 1 Reliability Evaluation Test Results

MAX2014ETA+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test (N	Note 1)				
	Ta = 150°C	DC Parameters	45	0	
	Biased	& functionality			
	Time = 192 hrs.	-			
Moisture Testing	(Note 2)				
HAST	Ta = 130°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 96hrs.				
Mechanical Stress	s (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010	-			

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data